128K x 9 Bit Separate I/O Synchronous Fast Static RAM

The Motorola MCM67Q709A is a 1,179,648 bit static random access memory, organized as 131,072 words of 9 bits. This device is fabricated using Motorola's high–performance silicon–gate BiCMOS technology. It features separate TTL input and output buffers, which are fully I/O compatible at 3.3 V, and incorporates input and output registers on board with high speed SRAM. It also features transparent–write and data pass–through capabilities.

The synchronous design allows for precise cycle control with the use of an external single clock (K). The addresses (A0-A16) data input (D0-D8), data output (Q0-Q8), write enable (W), chip enable (E), and output enable (G), are registered in on the <u>rising edge</u> of clock (K).

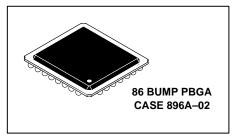
The control pins (E, W, G) function differently in comparison to most synchronous SRAMs. This device will not deselect with E high. The RAM remains active at all times. If E is registered high, the output pins (Q0–Q8) will be driven if G is registered low. The transparent write feature allows the output data to track the input data. E, G, and W must be asserted to perform a transparent write (write and pass–through). The input data is available at the ouputs on the next rising edge of clock (K).

The pass–through function is always enabled. E high disables the write to the array while allowing a <u>pass</u> through cycle to occur on the next rising edge of clock (K). Only a registered G high will three–state the outputs.

The MCM67Q709A is available in 86 bump surface mount PBGA (Plastic Ball Grid Array) package.

- Single 5 V ± 5% Power Supply
- Fast Cycle Times: 10/12 ns Max
- Single Clock Operation
- TTL Input and Output Levels (3.3 V I/O Compatible)
- · Address, Data Input, E, W, G Registers on Chip
- 100 MHz Maximum Clock Cycle Time
- Self Timed Write
- Separate Data Input and Output Pins
- Transparent–Write and Pass–Through
- High Output Drive Capability: 50 pF/Output at Rated Access Time
- Boundary Scan Implementation
- PBGA package for high speed operation

MCM67Q709A



PIN ASSIGNMENTS

	1	2	3	4	5	6	7	8	9
Α		⊖ E	⊖ W	O VCC	O SDI	O SDO	O A4	O A0	
В	O A16	O A14	⊖ G	O K	$^{\circ}_{VSS}$	O A6	O A2	$^{\circ}_{\text{VSS}}$	O D8
С	O D7	○ A15	O NC	$^{\circ}_{VSS}$	O VSS	$^{\circ}_{VSS}$	$^{\circ}_{VSS}$	○ Q 8	$^{\circ}_{VSS}$
D	o Vss	O Q7	O VSS	Vss	Vss	Vss	$^{\circ}_{SS}$	○ Q6	O D6
Ε	D5	$^{\circ}_{VSS}$	$^{\circ}_{\text{VSS}}$	$^{\circ}_{VSS}$	$^{\circ}_{VSS}$	O VSS	$^{\circ}_{VSS}$	$^{\circ}_{\text{SS}}$	° VCC
F	VCC	O Q5	$^{\circ}_{\text{SS}}$	$^{\circ}_{VSS}$	$^{\circ}_{VSS}$	$^{\circ}_{\text{VSS}}$	$^{\circ}_{VSS}$	O D4	O Q4
G	○ D3	○ Q 3	$^{\circ}_{VSS}$	$^{\circ}_{SS}$	$^{\circ}_{VSS}$	$^{\circ}_{VSS}$	\circ	O D2	O Q2
Н	o V _{SS}	O D1	O NC	$^{\circ}_{SS}$	O V _{SS}	$^{\circ}_{VSS}$	o V _{SS}	O D0	$^{\circ}_{VSS}$
J	O Q1	O A12	O A10	O VSS	O A9	O A8	O A5	O A1	○ Q 0
K		O A13	O A11	V _{SS} O SCK	VCC	O SE	O A7	O A3	/

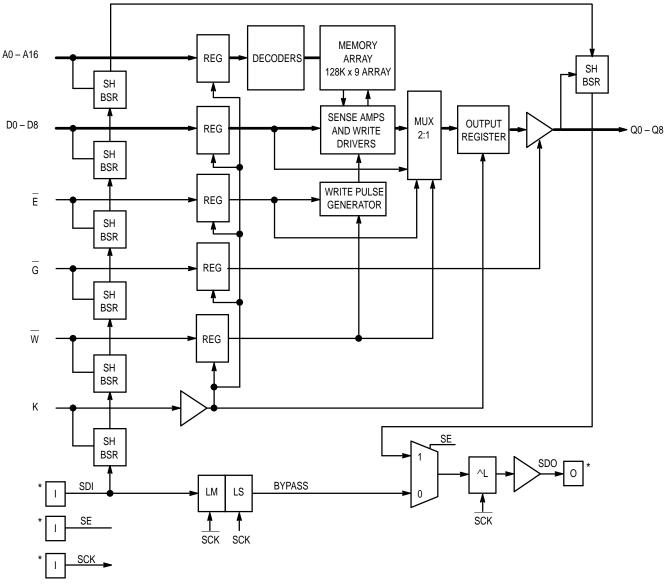
TOP VIEW 86 BUMP

Not to Scale

7/24/96



BLOCK DIAGRAM



NOTES:

- 1. Bypass mode is entered with SE low and SCK cycled.
- 2. SH BSR = Shadow Bypass Scan Register.
- 3. 39 bumps used in Boundary Scan. V_{SS}, V_{CC}, NC, SDI, SDO, SE, and SCK not used in Scan Path.
 4. SDO Output Sequence A6, A4, A2, A0, D8, Q8, D6, Q6, D4, Q4, D2, Q2, D0, Q0, A1, A3, A5, A7, A8, A9, A10, A11, A12, A13, Q1, D1, Q3, D3, Q5, D5, Q7, D7, A15, A16, A14, E, G, W, K.

^{*}Four added test pins.

TRUTH TABLE

E (t _n)	W (t _n)	G (t _{n + 1})	Mode	D0 – D8 (t _n)	Q0 – Q8 (t _{n + 1})	V _{CC} Current
L		L	Write and Pass Thru	Valid	D0 – D8 (t _n)	ICC
-	_	Н	Write	Valid	High–Z	Icc
Н		L	Pass Thru	Valid	D0 – D8 (t _n)	ICC
		Н	NOP	Don't Care	High–Z	Icc
Х	Н	L	Read	Don't Care	Q _{out} (t _n)	Icc
_ ^	11	Н	Read	Don't Care	High–Z	ICC

ABSOLUTE MAXIMUM RATINGS (See Note)

Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	- 0.5 to + 7.0	V
Voltage Relative to VSS for Any Pin Except VCC	V _{in} , V _{out}	- 0.5 to V _{CC} + 0.5	V
Output Current	l _{out}	± 30	mA
Power Dissipation	PD	1.5	W
Temperature Under Bias	T _{bias}	– 10 to + 85	°C
Operating Temperature	TA	0 to + 70	°C
Storage Temperature — Plastic	T _{stg}	- 55 to + 125	°C

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPER-ATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This is a synchronous device. All synchronous inputs must meet specified setup and hold times with stable logic levels for ALL rising edges of clock (K) while the device is selected.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to these high-impedance circuits.

DC OPERATING CONDITIONS AND CHARACTERISTICS

 $(V_{CC} = 5.0 \text{ V} \pm 5\%, T_A = 0 \text{ to} + 70^{\circ}\text{C}, \text{Unless Otherwise Noted})$

RECOMMENDED OPERATING CONDITIONS AND SUPPLY CURRENTS

Parameter	Symbol	Min	Max	Unit	
Supply Voltage (Operating Voltage Range)		VCC	4.75	5.25	V
Input High Voltage		VIH	2.2	V _{CC} + 0.3**	V
Input Low Voltage		VIL	- 0.5*	0.8	V
Input Leakage Current (All Inputs, V _{in} = 0 to V _{CC})		l _{lkg(l)}	_	± 1.0	μΑ
Output Leakage Current ($E = V_{IH}$, $V_{out} = 0$ to V_{CC})		l _{lkg(O)}	_	± 1.0	μΑ
AC Supply Current ($I_{Out} = 0 \text{ mA}$) ($V_{CC} = \text{max}, f = f_{max}$)	MCM67Q709A-10 ns MCM67Q709A-12 ns	ICCA	_ _	230 220	mA
Output Low Voltage (I _{OL} = + 8.0 mA)		VOL	_	0.4	V
Output High Voltage (I _{OH} = - 4.0 mA)		Voн	2.4	3.3	V

MOTOROLA FAST SRAM MCM67Q709A

CAPACITANCE (f = 1.0 MHz, dV = 3.0 V, $T_A = 25^{\circ}\text{C}$, Periodically Sampled Rather Than 100% Tested)

Parameter	Symbol	Max	Unit
Address and Data Input Capacitance	C _{in}	6	pF
Control Pin Input Capacitance	C _{in}	6	pF
Output Capacitance	C _{out}	8	pF

AC OPERATING CONDITIONS AND CHARACTERISTICS

(V_{CC} = 5.0 V \pm 5%, T_A = 0 to + 70°C, Unless Otherwise Noted)

Input Timing Measurement Reference Level 1.5	V	Output Timing Reference Level .	
Input Pulse Levels	V	Output Load	Figure 1A Unless Otherwise Noted
Input Rise/Fall Time	ns		

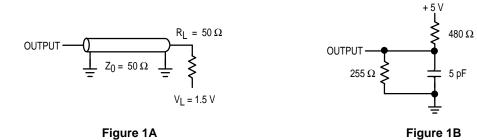
READ/WRITE CYCLE TIMING (See Notes 1, 2, and 3)

		МСМ67С	709A-10	MCM67Q709A-12			
Parameter	Symbol	Min	Max	Min	Max	Unit	Notes
Cycle Time	^t KHKH	10	_	12	_	ns	1
Clock Access Time	^t KHQV	_	5	_	6	ns	2
Clock Low Pulse Width	^t KLKH	4	_	4	_	ns	
Clock High Pulse Width	^t KHKL	4	_	4	_	ns	
Clock High to Data Output Invalid	^t KHQX	2	_	2	_	ns	
Clock High to Data Output High–Z	^t KHQZ	_	5	_	6	ns	
Setup Times: A W E G D0 – D8	tavkh twvkh tevkh tgvkh tdvkh	2	_	2	_	ns	3
Hold Times: A W E G D0 – D8	[†] KHAX [†] KHWX [†] KHEX [†] KHGX [†] KHDX	1	_	1	_	ns	3

NOTES:

- 1. All read and write cycles are referenced from K.
- 2. Valid data from Clock High will be the data stored at the address or the last valid read cycle.
- 3. This is a synchronous device. All synchronous inputs must meet the specified setup and hold times with stable logic levels for *ALL* rising edges of clock (K) while the device is selected.

AC SPEC LOADS

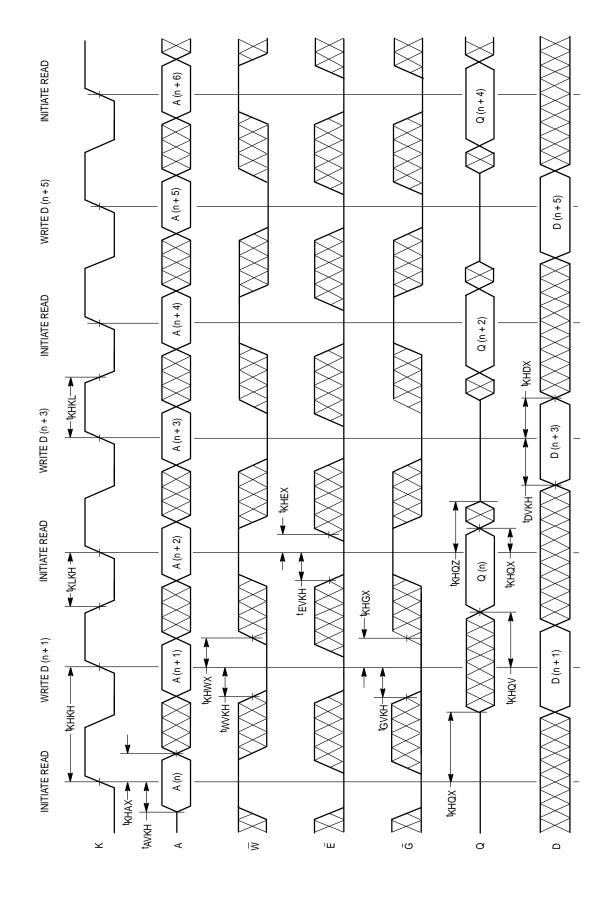


MCM67Q709A MOTOROLA FAST SRAM

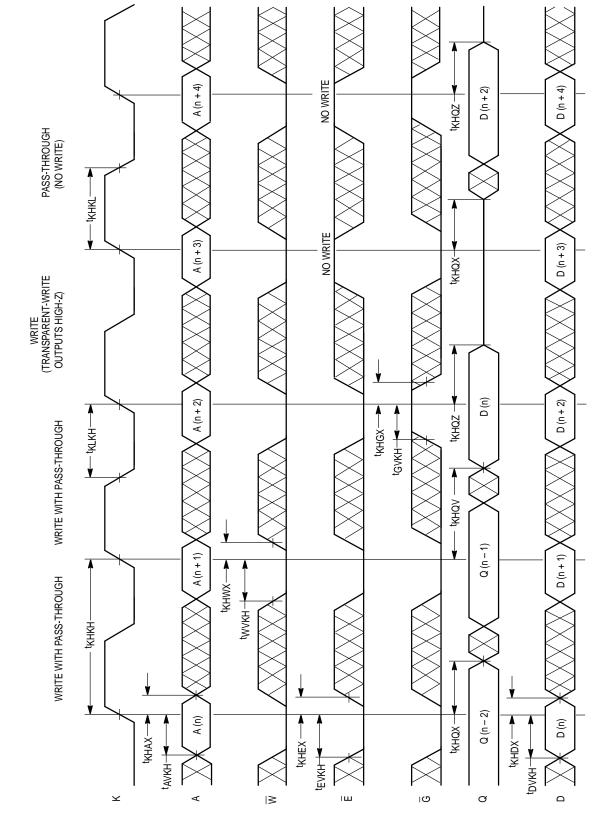
MCM67Q709A 5 MOTOROLA FAST SRAM

Ø

COMBINATION READ/WRITE CYCLE TIMING



TRANSPARENT-WRITE AND PASS-THROUGH CYCLE TIMING



MCM67Q709A 7 MOTOROLA FAST SRAM

BOUNDARY SCAN CYCLE TIMING

		MCM67Q709A-10		MCM67Q709A-10 MCM67Q709A-12		709A-12		
Parameter	Symbol	Min	Max	Min	Max	Unit	Notes	
Cycle Time	^t CHCH2	100	_	100	_	ns		
Clock High Pulse Width	^t CHCL2	40	_	40	_	ns		
Clock Low Pulse Width	[†] CLCH2	40	_	40	_	ns		
Scan Mode Setup Time	tss	10	_	10	_	ns	1	
Bypass Mode Setup Time	t _{BS}	10	_	10	_	ns	2	
Scan Mode Recovery Time	tSR	100	_	100	_	ns	3	
SCK Low to SE Hold High	tCLMH	10	_	10	_	ns	4	
SE High to SCK High Setup	tMHCH	10	_	10	_	ns	5	
SCK High to SE Low Hold Time	^t CHML	10	_	10	_	ns	6	
SDI Valid to SCK High Setup	^t IVCH	10	_	10	_	ns		
SCK High to SDI Don't Care	tCHIX	10	_	10	_	ns		
SCK Low to SDO Valid	tCLOV	_	20	_	20	ns		

NOTES:

- 1. The minimum delay required between ending normal operation and beginning scan operations.
- 2. The minimum delay required between ending Shift Mode and beginning Bypass Mode.
- 3. The minimum delay required before restarting normal RAM operation.
- 4. The minimum delay required before executing a Parallel Load operation.
- 5. The minimum delay required between a Parallel Load operation and a Shift.
- 6. Minimum Shift command hold time.

BOUNDARY SCAN

OVERVIEW

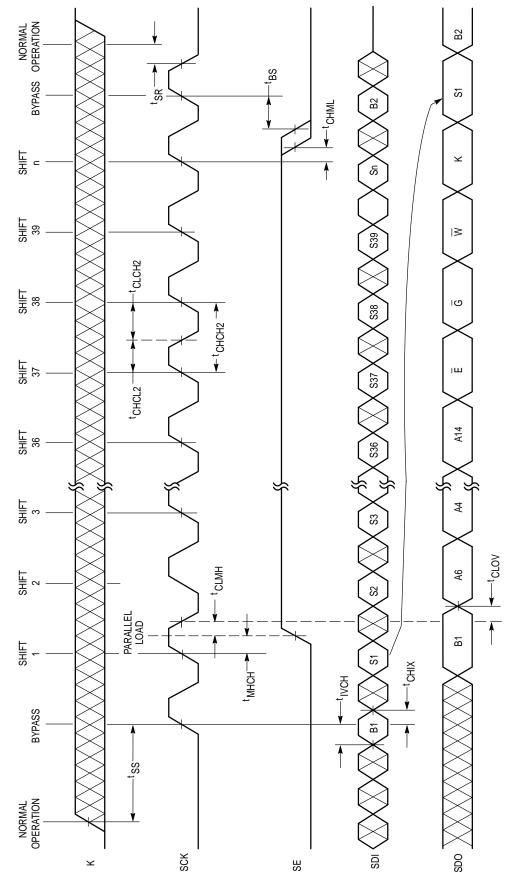
Boundary scan is a simple, non–intrusive scheme that allows verification of electrical continuity for each of a clocked RAM's logically active inputs and I/Os without adversely affecting RAM performance. Boundary scan allows the user to monitor the logic levels applied to each signal I/O on the RAM, and to shift them out in a serial bit stream.

OPERATION

Boundary scan requires four signal pins for implementation: Scan Data In (SDI), Scan Data Out (SDO), Scan Clock (SCK, active high), and Scan Enable (SE, active high). Boundary scan provides three modes of operation: (1) normal RAM operation, (2) scan, and (3) bypass. For normal RAM operation SCK and SE must be held low. The RAM will always return to normal operation immediately after the RAM receives a rising edge of the RAM input clock (K) with SCK and SE held low. To enter scan mode, SCK is activated. The first rising edge of SCK is used to latch in the data on the scan registers. SE is then driven high to disable additional input data from entering the scan registers. Every falling edge of SCK serially shifts data through the scan registers and onto the SDO pin. To enter bypass mode simply exercise SCK with SE held low. In this mode SDI is sampled on the rising edge of SCK. The level found on SDI is then driven out on SDO on the next falling edge of SCK.

MCM67Q709A MOTOROLA FAST SRAM

BOUNDARY SCAN TIMING DIAGRAM



B1 and B2 = Bypass Serial Data from outside source
S1 - Sn + 1 = Serial Scan Data from outside source
S1 - Sn + 1 = Serial Scan Data from outside source
S1 - Sn = RAMs Input Register contents
S2 - Sn - RAMs Input Register Contents
S2 - Sn - RAMs Input Register Contents
S2 - RAMs Input Register Contents
S2 - RAMs Input Register Contents
S2 - RAMs Input Register Contents

MOTOROLA FAST SRAM MCM67Q709A

ORDERING INFORMATION (Order by Full Part Number)

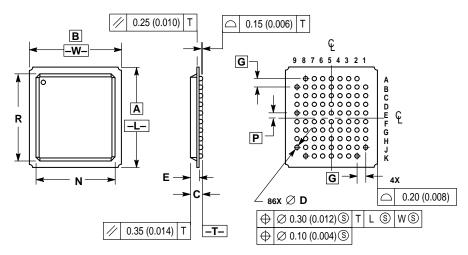
<u>MÇM</u> 67Q	709A XX	<u> </u>	<u>X</u>	
Motorola Memory Prefix				Shipping Method (R = Tape and Reel, Blank = Trays)
Part Number				Speed (10 = 10 ns, 12 = 12 ns)
				Package (ZP = PBGA)

 $\begin{array}{ccc} \text{Full Part Numbers} - \text{MCM67Q709AZP10} & \text{MCM67Q709AZP12} \\ & \text{MCM67Q709AZP10R} & \text{MCM67Q709AZP12R} \end{array}$

MCM67Q709A MOTOROLA FAST SRAM

PACKAGE DIMENSIONS

ZP PACKAGE 86 PBGA **CASE 896A-02**



- NOTES:
 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIN	METERS	INC	HES			
DIM	MIN	MAX	MIN	MAX			
Α	17.78	BSC	0.700	BSC			
В	16.26	BSC	0.640 BSC				
С	1.84	2.44	0.073	0.096			
D	0.69	0.81	0.028	0.031			
Е	1.33	1.73	0.053	0.068			
G	1.524	BSC	0.060 BSC				
N	N 13.80 14.20		0.544 0.559				
Р	0.762	BSC	0.030 BSC				
R	15 20	15.60	0.602	0.617			

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